



No.3446A

2SK1443

N-Channel Silicon MOSFET

Ultrahigh-Speed
Switching Applications**Features**

- Low ON-state resistance.
- Ultrahigh-speed switching.
- Micaless package facilitating easy mounting.

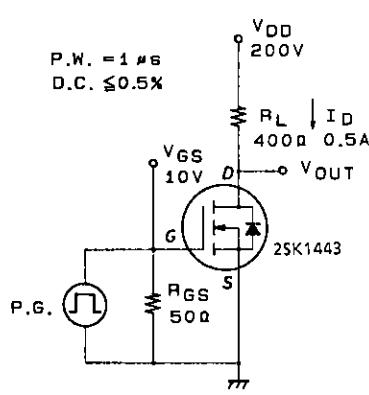
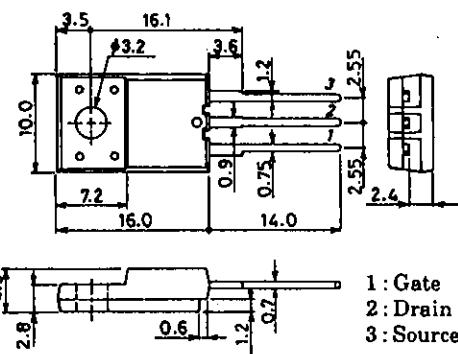
Absolute Maximum Ratings at Ta=25°C

			unit
Drain-to-Source Voltage	V _{DSS}	450	V
Gate-to-Source Voltage	V _{GSS}	±30	V
Drain Current(DC)	I _D	1	A
Drain Current(Pulse)	I _{DP}	4	A
Allowable Power Dissipation	P _D	2.0	W
Channel Temperature	T _{ch}	20	W
Storage Temperature	T _{stg}	150	°C
		-55 to +150	°C

Electrical Characteristics at Ta=25°C

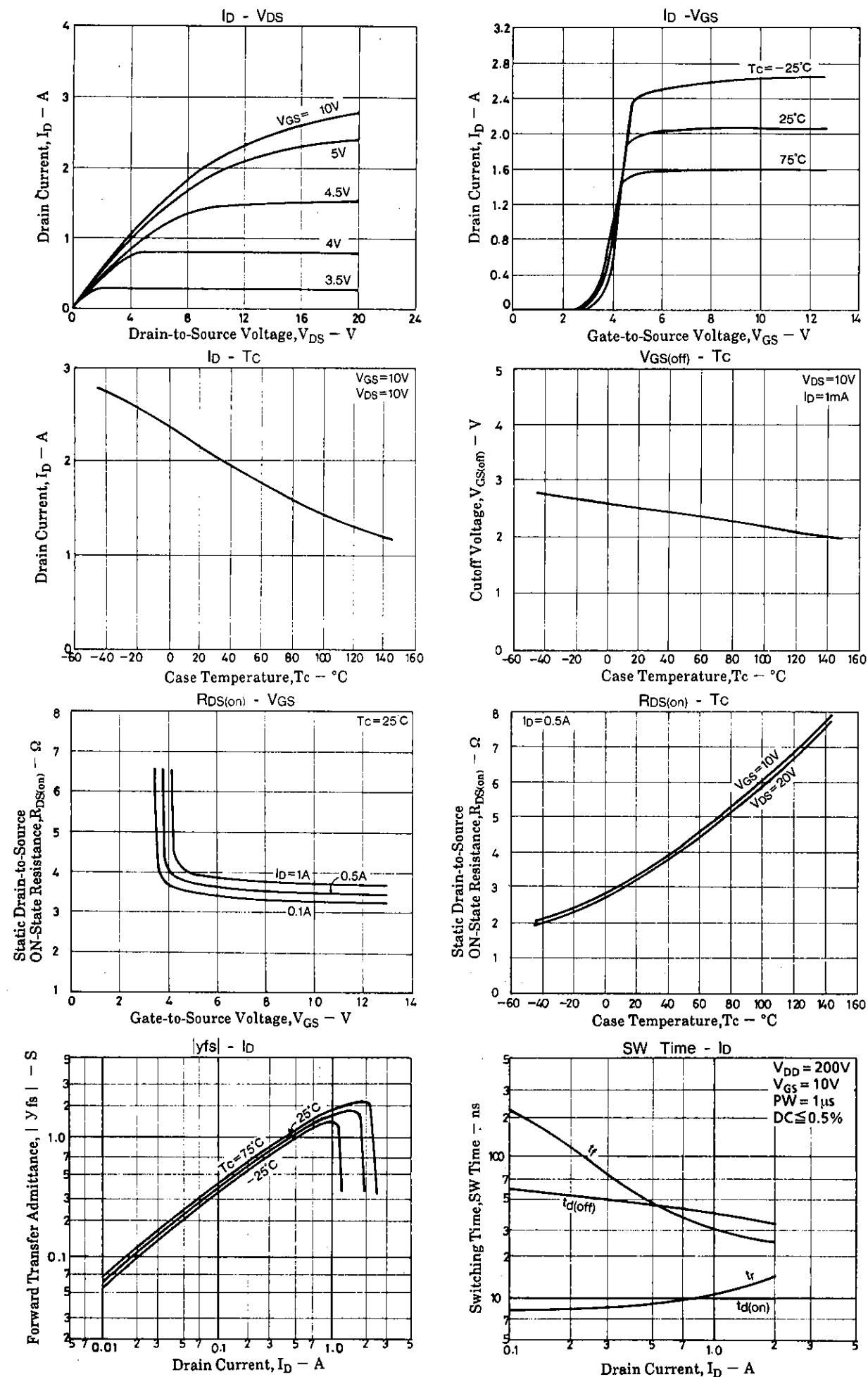
			min	typ	max	unit
D-S Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0	450			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =450V, V _{GS} =0			1.0	mA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±30V, V _{DS} =0			±100	nA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	2.0		3.0	V
Forward Transfer Admittance	Y _{fs}	V _{DS} =10V, I _D =0.5A	0.6	1.2		S
Static Drain-to-Source	R _{DS(on)}	I _D =0.5A, V _{GS} =10V		3.5	4.5	Ω
ON-State Resistance						
Input Capacitance	C _{iss}	V _{DS} =20V, f=1MHz	250			pF
Output Capacitance	C _{oss}	V _{DS} =20V, f=1MHz	40			pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =20V, f=1MHz	8			pF
Turn-ON Delay Time	t _{d(on)}		10			ns
Rise Time	t _r	I _D =0.5A, V _{GS} =10V	9			ns
Turn-OFF Delay Time	t _{d(off)}	V _{DD} =200V, R _{GS} =50Ω	45			ns
Fall Time	t _f		45			ns
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0			1.8	V

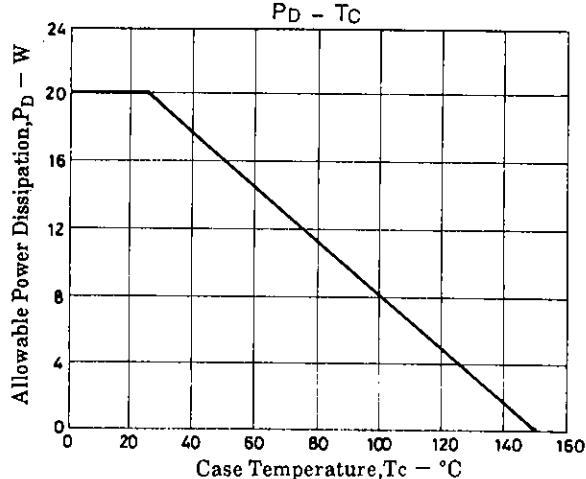
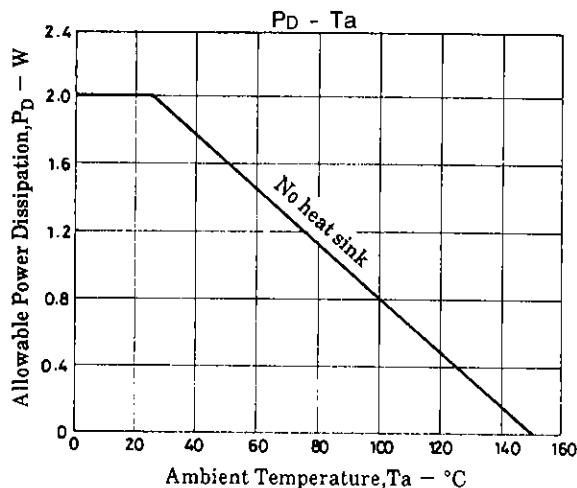
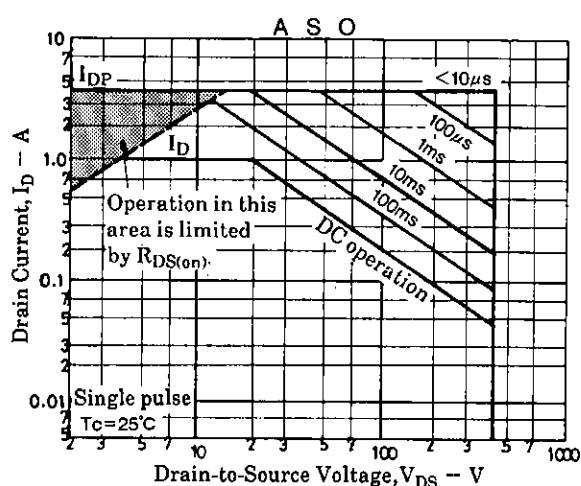
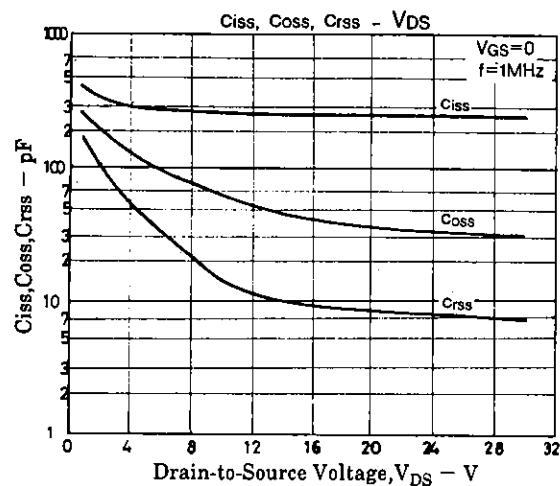
(Note) Be careful in handling the 2SK1443 because it has no protection diode between gate and source.

Switching Time Test Circuit**Package Dimensions 2078B**
(unit : mm)

SANYO : TO-220FI(LS)

SANYO Electric Co., Ltd. Semiconductor Business Headquarters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN





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